

Data Sheet

0.1 GHz to 50 GHz, GaAs, MMIC Reflective SPDT Switch

HMC986A

FEATURES

Broadband frequency range: 0.1 GHz to 50 GHz Reflective 50 Ω design Low insertion loss: 2.3 dB at 50 GHz High isolation: 30 dB at 50 GHz High input linearity 1 dB power compression (P1dB): 28 dBm typical Third-order intercept (IP3): 40 dBm typical High power handling 27 dBm through path

13-pad, 0.98 mm \times 0.75 mm \times 0.1 mm, CHIP

APPLICATIONS

Test instrumentation

Microwave radios and very small aperture terminals (VSATs) Military radios, radars, and electronic counter measures (ECMs) Broadband telecommunications systems

GENERAL DESCRIPTION

The HMC986A is a reflective, single-pole, double throw (SPDT) switch, manufactured using a gallium arsenide (GaAs) process. This switch typically provides low insertion loss of 2.3 dB and high isolation of 30 dB in broadband frequency range from 0.1 GHz to 50 GHz.

FUNCTIONAL BLOCK DIAGRAM

This switch operates with two negative logic control voltages from -5 V to -3 V. All electrical performance data is acquired with the RFx pads of the HMC986A connected to 50 Ω transmission lines via one 3.0 mil × 0.5 mil ribbon bond of minimal length.

Rev. B

Document Feedback

Information furnished by Analog Devices is believed to be accurate and reliable. However, no responsibility is assumed by Analog Devices for its use, nor for any infringements of patents or other rights of third parties that may result from its use. Specifications subject to change without notice. No license is granted by implication or otherwise under any patent or patent rights of Analog Devices. Trademarks and registered trademarks are the property of their respective owners.

TABLE OF CONTENTS

Features	1
Applications	1
Functional Block Diagram	1
General Description	1
Revision History	2
Specifications	3
Absolute Maximum Ratings	4
Power Derating Curve	4
ESD Caution	4
Pin Configuration and Function Descriptions	5
Interface Schematics	5

REVISION HISTORY

7/2019—Rev. A to Rev. B

Deleted Figure 1; Renumbered Sequentially	1
Added Figure 1; Renumbered Sequentially	1
Changes to Features Section and General Description Section	1
Changes to Specifications Section and Table 1	3
Added Figure 2, Thermal Resistance Section, and Table 3;	
Renumbered Sequentially	4
Changes to Table 2	4
Added Figure 3, Figure 4, and Figure 5	5
Changes to Table 4	5
Added Figure 6 to Figure 9	6
Added Figure 10 to Figure 15	•••

Typical Performance Characteristics	6
Insertion Loss, Return Loss, and Isolation	6
Input Power Compression (P1dB) and Third-Order Interce (IP3)	ept 7
Theory of Operation	9
Applications Information	10
Mounting and Bonding Techniques	10
Assembly Diagram	10
Outline Dimensions	11
Ordering Guide	11

SPECIFICATIONS

 $V_{\rm CTL}$ = –5 V to –3 V or 0V, $T_{\rm DIE}$ = 25°C, 50 Ω system, unless otherwise noted.

Table 1.

Parameter	Symbol	Test Conditions/Comments	Min	Тур	Max	Unit
BROADBAND FREQUENCY RANGE	f		0.1		50	GHz
INSERTION LOSS		0.1 GHz to 18 GHz		1.7	2.3	dB
		18 GHz to 40 GHz		1.9	2.5	dB
		40 GHz to 50 GHz		2.3	2.8	dB
ISOLATION						
Between RFC and RF1 to RF2		0.1 GHz to 18 GHz	30	36		dB
		18 GHz to 40 GHz	25	32		dB
		40 GHz to 50 GHz	22	30		dB
RETURN LOSS						
RFC and RF1/RF2		0.1 GHz to 18 GHz		15		dB
		18 GHz to 40 GHz		15		dB
		40 GHz to 50 GHz		13		dB
SWITCHING CHARACTERISTICS						
Rise and Fall Time	trise, t _{FALL}	10% to 90% of RF output		2		ns
On and Off Time	ton, toff	50% V _{CTL} to 90% of RF output		11		ns
INPUT LINEARITY ¹		2 GHz to 50 GHz				
1 dB Compression	P1dB	$V_{CTL} = -5 V/0 V$	22	28		dBm
		$V_{CTL} = -3 \text{ V/0 V}$		25		dBm
0.1 dB Compression	P0.1dB	$V_{CTL} = -5 V/0 V$		25		dBm
		$V_{CTL} = -3 V/0 V$		22		dBm
Third-Order Intercept	IP3	0 dBm per tone, 1 MHz spacing				
		$V_{CTL} = -5 V/0 V$		40		dBm
		$V_{CTL} = -3 \text{ V/0 V}$		40		dBm
DIGITAL CONTROL INPUTS		V_1 and V_2 pins				
Voltage	V _{CTL}					
Low	VINL		-0.2	0	+0.2	V
High	V _{INH}		-5		-3	V
Current	Ість					
Low	I _{INL}	$V_{CTL} = 0 V$		1		μA
High	I _{INH}	$V_{CTL} = -5 V \text{ to } -3 V$		10		μA

¹ For input linearity performance over frequency, see Figure 11 to Figure 13.

ABSOLUTE MAXIMUM RATINGS

Table 2.

Parameter	Rating
Digital Control Input Voltage	–5.5 V to +0.5 V
RF Input Power ¹ (f = 2 GHz to 50 GHz, $T_{DIE} = 85^{\circ}C$)	
$V_{CTL} = -5 \text{ V/0 V}$	
Through Path	27 dBm
Hot Switching	24 dBm
$V_{CTL} = -3 V/0 V$	
Through Path	24 dBm
Hot Switching	21 dBm
Temperature	
Junction Temperature, TJ	150°C
Die Bottom Temperature Range, TDIE	–55°C to +85°C
Storage Temperature Range	–65°C to +150°C
ESD Sensitivity	
Human Body Model (HBM)	150 V (Class 0)

¹ For power derating at frequencies less than 2 GHz, see Figure 2.

Stresses at or above those listed under Absolute Maximum Ratings may cause permanent damage to the product. This is a stress rating only; functional operation of the product at these or any other conditions above those indicated in the operational section of this specification is not implied. Operation beyond the maximum operating conditions for extended periods may affect product reliability.

POWER DERATING CURVE



THERMAL RESISTANCE

Thermal performance is directly linked to printed circuit board (PCB) design and operating environment. Close attention to PCB thermal design is required.

 θ_{JC} is the junction to case thermal resistance.

Table 3.

Package Option	θ _{JC}	Unit	
C-13-1	260	°C/W	

ESD CAUTION



ESD (electrostatic discharge) sensitive device. Charged devices and circuit boards can discharge without detection. Although this product features patented or proprietary protection circuitry, damage may occur on devices subjected to high energy ESD. Therefore, proper ESD precautions should be taken to avoid performance degradation or loss of functionality.

PIN CONFIGURATION AND FUNCTION DESCRIPTIONS



Figure 3. Pin Configuration

Table 4. Pad Function Descriptions

Pad No.	Mnemonic	Description
1, 3, 4, 6, 7, 9	GND	Analog Ground. These pads are connected to die backside ground and can be used to achieve a ground to signal to ground interface for optimum RF performance. The performance of the HMC986A is measured with a Ground-Signal-Ground interface on RF1, RFC, and RF2.
2	RF1	RF Throw Pad 1. This pad is dc-coupled to 0 V and ac matched to 50 Ω . No dc blocking capacitor is necessary when the RF line potential is equal to 0 V dc. See Figure 4 for the interface schematic.
5	RFC	RF Common Pad. This pad is dc-coupled to 0 V and ac matched to 50 Ω . No dc blocking capacitor is necessary when the RF line potential is equal to 0 V dc. See Figure 4 for the interface schematic.
8	RF2	RF Throw Pad 2. This pad is dc-coupled to 0 V and ac matched to 50 Ω . No dc blocking capacitor is necessary when the RF line potential is equal to 0 V dc. See Figure 4 for the interface schematic.
10, 13	GND	Ground. These pads are connected to die backside ground and are optional for use as V_1 , V_2 control signal ground return.
11	V ₂	Control Input 2. See Table 5. See Figure 5 for the interface schematic.
12	V ₁	Control Input 1. See Table 5. See Figure 5 for the interface schematic.
Die Bottom	GND	Ground. The Die bottom must be attached directly to the ground plane eutectically or with conductive epoxy.

INTERFACE SCHEMATICS

RFC, RF1, RF2 ΤŧΓ 606-003

Figure 4. RFC to RF1/RF2 Interface Schematic

 $V_1, O = 1k\Omega$ $V_2 O = 0$: C = 1pF 3606-

Figure 5. V_1 and V_2 Control Input Interface Schematic

TYPICAL PERFORMANCE CHARACTERISTICS INSERTION LOSS, RETURN LOSS, AND ISOLATION



Figure 6. Insertion Loss Between RFC and RF1 vs. Frequency over Temperature



Figure 7. Isolation Between RFC and RF1/RF2 vs. Frequency



Figure 8. Insertion Loss Between RFC and RF1/RF2 vs. Frequency



Figure 9. Return Loss for RFC, RF1 ON and RF2 ON vs. Frequency

Data Sheet

HMC986A

INPUT POWER COMPRESSION (P1dB) AND THIRD-ORDER INTERCEPT (IP3)



Figure 10. Input P0.1dB vs. Frequency over Temperature, $V_{CTL} = -5 V$



Figure 11. Input P0.1dB vs Low Frequency over Temperature, $V_{CTL} = -5 V$



Figure 12. Input P1dB vs. Frequency over Temperature, $V_{CTL} = -5 V$



Figure 13. Input P0.1dB vs Frequency over Temperature, $V_{CTL} = -3 V$



Figure 14. Input P0.1dB vs. Low Frequency over Temperature, $V_{CTL} = -3 V$



Figure 15 Input P1dB vs. Low Frequency over Temperature, $V_{CTL} = -3 V$

HMC986A



Figure 16. Input P1dB vs. Low Frequency over Temperature, $V_{CTL} = -5 V$



Figure 17. Input IP3 vs Frequency over Temperature, $V_{CTL} = -5 V$



Figure 18. Input IP3 vs. Low Frequency over Temperature, $V_{CTL} = -5 V$



Figure 19. Input P1dB vs. Low Frequency over Temperature, $V_{CTL} = -3 V$







Figure 21 Input IP3 vs. Low Frequency over Temperature, $V_{CTL} = -3 V$

THEORY OF OPERATION

The HMC986A requires two logic control inputs at the $\rm V_1$ and $\rm V_2$ pads to control the state of the RF paths.

Depending on the logic level applied to the V_1 and V_2 pads, one RF path is in the insertion loss state while the other path is in an isolation state (see Table 5). The insertion loss path conducts the RF signal between the RF throw pad and RF common pad. The unselected RF port of the HMC986A is reflective. The isolation path provides high isolation between the unselected port and the insertion loss path.

The ideal power-up sequence is as follows:

- 1. Ground to the die bottom.
- 2. Power up the digital control inputs. The relative order of the logic control inputs is not important. However, powering the digital control inputs before the V_{CTL} supply can inadvertently become forward-biased and damage the internal electrostatic discharge (ESD) protection structures.
- 3. Apply an RF input signal. The design is bidirectional; the RF input signal can be applied to the RFC pad while the RF throw pads are the outputs or the RF input signal can be applied to the RF throw pads while the RFC pad is the output. All of the RF pads are dc-coupled to 0 V, and no dc blocking is required at the RF pads when the RF line potential is equal to 0 V.

The power-down sequence is the reverse of the power-up sequence.

Table 5. Control Voltage Truth Table

Digital Control Input			
V ₁	V ₂	RF1 to RFC	RF2 to RFC
High	Low	Insertion loss (on)	Isolation (off)
Low	High	Isolation (off)	Insertion loss (on)

APPLICATIONS INFORMATION mounting and bonding techniques

The HMC986A is back metallized and must be attached directly to the ground plane with gold tin (AuSn) eutectic preforms or with electrically conductive epoxy.

The die thickness is 0.102 mm (4 mil). The 50 Ω microstrip transmission lines on 0.127 mm (5 mil) thick alumina thin film substrates are recommended for bringing RF to and from the HMC986A (see Figure 22).

The HMC986A must be raised 0.150 mm (6 mil) when using 0.254 mm (10 mil) thick alumina thin film substrates so that the surface of the HMC986A is coplanar with the surface of the substrate, which can be achieved by attaching the 0.102 mm (4 mil) thick die to a 0.15 mm (6 mil) thick molybdenum heat spreader (moly tab). The moly tab is then attached to the ground plane (see Figure 23).

Microstrip substrates are placed as close to the HMC986A as possible to minimize bond length. Typical die to substrate spacing is 0.076 mm (3 mil).

RF bonds made with 3 mil \times 5 mil ribbon are recommended. DC bonds made with 1 mil diameter wire are recommended. All bonds must be as short as possible.



Figure 23. Bonding RF Pads to 10 mil Substrate

ASSEMBLY DIAGRAM

An assembly diagram of the HMC986A is shown in Figure 24.



Figure 24. Die Assembly Diagram

OUTLINE DIMENSIONS



Dimensions shown in millimeters

ORDERING GUIDE

Model ^{1, 2}	Temperature Range	Package Description	Package Option
HMC986A	–55°C to +85°C	13-Pad Bare Die [CHIP]	C-13-1
HMC986A-SX	–55°C to +85°C	13-Pad Bare Die [CHIP]	C-13-1

¹ The HMC986A is a RoHS-compliant part.

² The HMC986A-SX is a sample order model.



Rev. B | Page 11 of 11

X-ON Electronics

Largest Supplier of Electrical and Electronic Components

Click to view similar products for RF Switch ICs category:

Click to view products by Analog Devices manufacturer:

Other Similar products are found below :

MASW-008853-TR3000 BGS13SN8E6327XTSA1 BGSX210MA18E6327XTSA1 SKY13446-374LF SW-227-PIN CG2185X2 CG2415M6 MA4SW410B-1 MASW-002102-13580G MASW-008543-001SMB MASW-008955-TR3000 TGS4307 BGS 12PL6 E6327 BGS1414MN20E6327XTSA1 BGS1515MN20E6327XTSA1 BGSA11GN10E6327XTSA1 BGSX28MA18E6327XTSA1 HMC199AMS8 SKY13374-397LF SKY13453-385LF CG2415M6-C2 HMC986A-SX SW-314-PIN UPG2162T5N-E2-A SKY13416-485LF MASWSS0204TR-3000 MASWSS0201TR MASWSS0181TR-3000 MASW-007588-TR3000 MASW-004103-13655P MASW-003102-13590G MASWSS0202TR-3000 MA4SW310B-1 MA4SW110 SW-313-PIN CG2430X1 SKY13321-360LF SKY13405-490LF SKYA21001 BGSF 18DM20 E6327 SKY13415-485LF MMS008PP3 BGS13PN10E6327XTSA1 SKY13319-374LF BGS14PN10E6327XTSA1 SKY12213-478LF SKY13404-466LF MASW-011060-TR0500 SKYA21024 SKY85601-11